

MOSFETs Silicon N-Channel MOS (U-MOSVII-H)

TPC8059-H

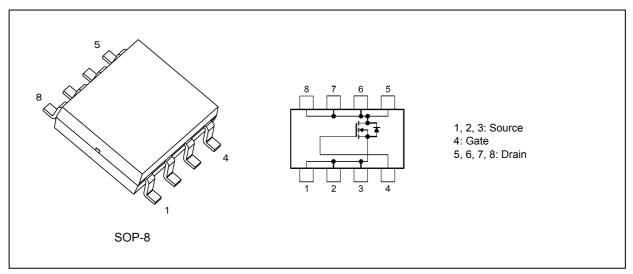
1. Applications

- · High-Efficiency DC-DC Converters
- · Notebook PCs
- · Mobile Handsets

2. Features

- (1) Small footprint due to a small and thin package
- (2) High-speed switching
- (3) Small gate change: $Q_{SW} = 9.1 \text{ nC}$ (typ.)
- (4) Low drain-source on-resistance: $R_{DS(ON)} = 4.0 \text{ m}\Omega$ (typ.) ($V_{GS} = 4.5 \text{ V}$)
- (5) Low leakage current: $I_{DSS} = 10 \mu A \text{ (max) (V}_{DS} = 30 \text{ V)}$
- (6) Enhancement mode: $V_{th} = 1.3 \text{ to } 2.3 \text{ V } (V_{DS} = 10 \text{ V}, I_D = 0.5 \text{ mA})$

3. Packaging and Internal Circuit



4. Absolute Maximum Ratings (Note) (T_a = 25°C unless otherwise specified)

Character	Symbol	Rating	Unit		
Drain-source voltage			V_{DSS}	30	V
Gate-source voltage			V _{GSS}	±20	
Drain current (DC)		(Note 1)	I _D	18	Α
Drain current (pulsed)		(Note 1)	I _{DP}	72	
Power dissipation	(t = 10 s)	(Note 2)	P _D	1.9	W
Power dissipation	(t = 10 s)	(Note 3)	P _D	1.0	W
Single-pulse avalanche energy		(Note 4)	E _{AS}	421	mJ
Avalanche current			I _{AR}	18	Α
Channel temperature			T _{ch}	150	°C
Storage temperature			T _{stg}	-55 to 150]

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).



5. Thermal Characteristics

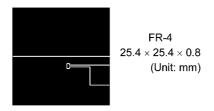
Characteristics				Max	Unit
Channel-to-ambient thermal resistance	(t = 10 s)	(Note 2)	R _{th(ch-a)}	65.7	°C/W
Channel-to-ambient thermal resistance	(t = 10 s)	(Note 3)	R _{th(ch-a)}	125	°C/W

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: Device mounted on a glass-epoxy board (a), Figure 5.1

Note 3: Device mounted on a glass-epoxy board (b), Figure 5.2

Note 4: V_{DD} = 24 V, T_{ch} = 25°C (initial), L = 1.0 mH, R_G = 1 Ω , I_{AR} = 18 A



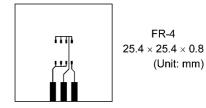


Fig. 5.1 Device Mounted on a Glass-Epoxy Board (a)

Fig. 5.2 Device Mounted on a Glass-Epoxy Board (b)

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.



6. Electrical Characteristics (T_a = 25°C unless otherwise specified)

6.1. Static Characteristics

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I _{GSS}	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±0.1	μΑ
Drain cut-off current	I _{DSS}	V _{DS} = 30 V, V _{GS} = 0 V	_	_	10	
Drain-source breakdown voltage	V _{(BR)DSS}	I _D = 10 mA, V _{GS} = 0 V	30	_	_	V
	V _{(BR)DSX}	I _D = 10 mA, V _{GS} = -20 V	15	_	_	
Gate threshold voltage	V_{th}	V _{DS} = 10 V, I _D = 0.5 mA	1.3	_	2.3	
Drain-source on-resistance	R _{DS(ON)}	V _{GS} = 4.5 V, I _D = 9 A		4.0	5.0	mΩ
		V _{GS} = 10 V, I _D = 9 A	_	3.1	4.0	

6.2. Dynamic Characteristics

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C _{iss}	V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz	_	2900	3500	pF
Reverse transfer capacitance	C _{rss}		_	150	230	
Output capacitance	C _{oss}		_	530	_	
Gate resistance	r _g	V _{DS} = 10 V, V _{GS} = 0 V, f = 5 MHz	_	1.4	2.1	Ω
Switching time (rise time)	t _r	See Figure 6.2.1.	_	3.2	_	ns
Switching time (turn-on time)	t _{on}		_	12	_	
Switching time (fall time)	t _f		_	8.0	_	
Switching time (turn-off time)	t _{off}		_	42		

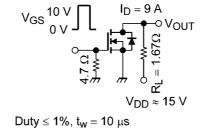


Fig. 6.2.1 Switching Time Test Circuit

6.3. Gate Charge Characteristics

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge	Qg	$V_{DD} \approx 24 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 18 \text{ A}$	_	41	_	nC
(gate-source plus gate-drain)		$V_{DD} \approx 24 \text{ V}, V_{GS} = 5 \text{ V}, I_{D} = 18 \text{ A}$		21	_	
Gate-source charge 1	Q _{gs1}	$V_{DD} \approx 24 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 18 \text{ A}$	_	8.9	_	
Gate-drain charge	Q _{gd}		_	4.8	_	
Gate switch charge	Q _{SW}		_	9.1	_	

6.4. Source-Drain Characteristics

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Pulsed reverse drain current	(Note 5)	I _{DRP}	_	_	_	72	Α
Diode forward voltage		V_{DSF}	I _{DR} = 18 A, V _{GS} = 0 V	_	_	-1.2	V

Note 5: Ensure that the channel temperature does not exceed 150°C.



7. Marking(Note)

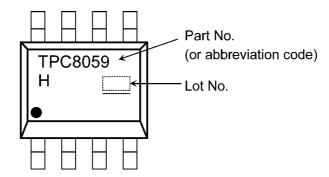


Fig. 7.1 Marking

Note: A line under a Lot No. identifies the indication of product Labels.

Not underlined: [[Pb]]/INCLUDES > MCV

Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.

The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

8. Characteristics Curves (Note)

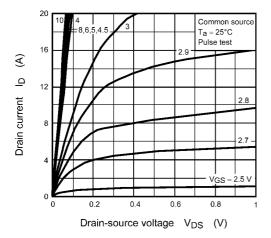


Fig. 8.1 I_D - V_{DS}

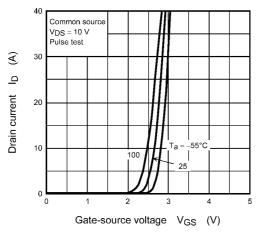


Fig. 8.3 I_D - V_{GS}

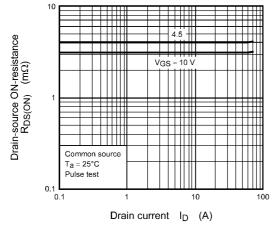


Fig. 8.5 R_{DS(ON)} - I_D

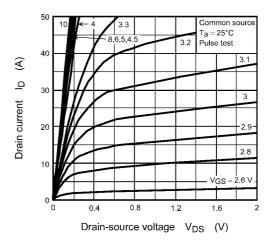


Fig. 8.2 I_D - V_{DS}

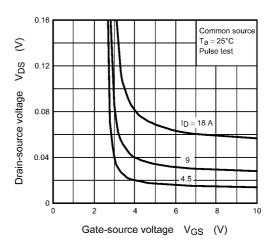


Fig. 8.4 VDS - VGS

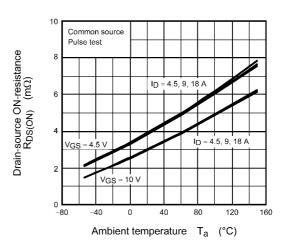


Fig. 8.6 R_{DS(ON)} - T_a

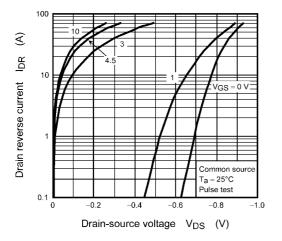


Fig. 8.7 I_{DR} - V_{DS}

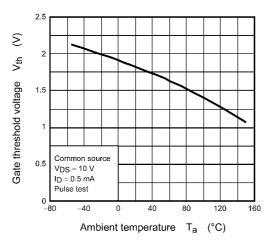


Fig. 8.9 Vth - Ta

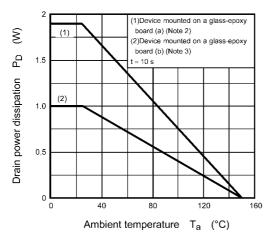


Fig. 8.11 P_D - T_a (Guaranteed Maximum)

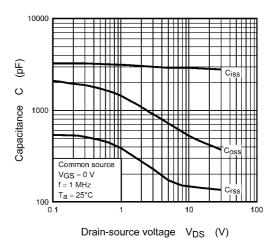


Fig. 8.8 Capacitance - V_{DS}

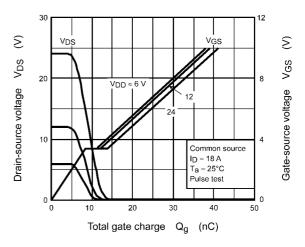


Fig. 8.10 Dynamic Input/Output Characteristics

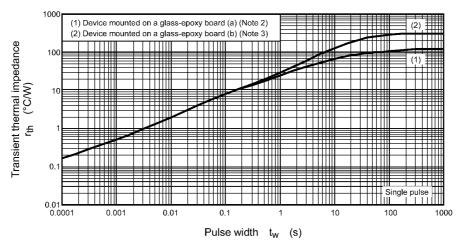


Fig. 8.12 r_{th} - t_w (Guaranteed Maximum)

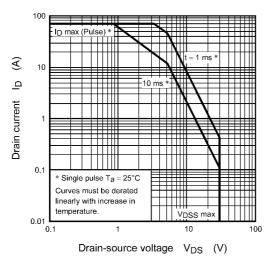


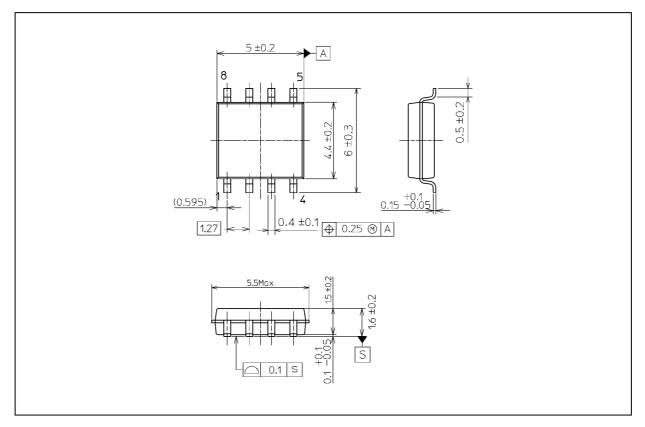
Fig. 8.13 Safe Operating Area (Guaranteed Maximum)

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



Package Dimensions

Unit: mm



Weight: 0.085 g (typ.)

Package Name(s)
TOSHIBA: 2-6J1S
Nickname: SOP-8



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